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	Application No.	Applicant(s)	-(an)
Al-4in- of Allowshills	10/743,783	ISHIMARU ET AL.	_(ev/
Notice of Allowability	Examiner	Art Unit	
	ANH PHUNG	2824	
The MAILING DATE of this communication ap All claims being allowable, PROSECUTION ON THE MERITS herewith (or previously mailed), a Notice of Allowance (PTOL-8 NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT of the Office or upon petition by the applicant. See 37 CFR 1.3	IS (OR REMAINS) CLOSED in IS) or other appropriate commu RIGHTS. This application is s	this application. If not included inication will be mailed in due c	d ourse. THIS
1. This communication is responsive to			
2. ☑ The allowed claim(s) is/are <u>1-42</u> .			
3. A The drawings filed on 24 December 2003 are accepted I	by the Examiner.		
 4. Acknowledgment is made of a claim for foreign priority a) All b) Some* c) None of the: 1. Certified copies of the priority documents hat 2. Certified copies of the priority documents hat 3. Copies of the certified copies of the priority of International Bureau (PCT Rule 17.2(a)). * Certified copies not received: Applicant has THREE MONTHS FROM THE "MAILING DATE noted below. Failure to timely comply will result in ABANDON THIS THREE-MONTH PERIOD IS NOT EXTENDABLE. 	ave been received. ave been received in Application documents have been received E" of this communication to file	n No I in this national stage applicati	
5. A SUBSTITUTE OATH OR DECLARATION must be sub INFORMAL PATENT APPLICATION (PTO-152) which g			OTICE OF
6. ☐ CORRECTED DRAWINGS (as "replacement sheets") m (a) ☐ including changes required by the Notice of Draftspot 1) ☐ hereto or 2) ☐ to Paper No./Mail Date (b) ☐ including changes required by the attached Examined Paper No./Mail Date Identifying Indicia such as the application number (see 37 CFF each sheet. Replacement sheet(s) should be labeled as such in 7. ☐ DEPOSIT OF and/or INFORMATION about the department of Examiner's comment regarding REQUIREMEN	erson's Patent Drawing Review er's Amendment / Comment or 1.84(c)) should be written on the the header according to 37 CF posit of BIOLOGICAL MATE	in the Office action of the drawings in the front (not the left 1.121(d). ERIAL must be submitted. No	
 Attachment(s) 1. ☑ Notice of References Cited (PTO-892) 2. ☐ Notice of Draftperson's Patent Drawing Review (PTO-948) 3. ☑ Information Disclosure Statements (PTO-1449 or PTO/St Paper No./Mail Date 4/27/04) 4. ☐ Examiner's Comment Regarding Requirement for Deposi of Biological Material 	6. ☐ Interview St. Paper No./ Payors), 7. ☐ Examiner's t 8. ☒ Examiner's 9. ☒ Other <u>Searce</u>	formal Patent Application (PTO ummary (PTO-413), Mail Date Amendment/Comment Statement of Reasons for Alloveh History. ANH PHUNG	·
		ANH PHUNG PRIMARY EXAMINER	

DETAILED ACTION

1. This Office Action is responsive to the U.S. Application Ser. No. 10/743,783 filed on December 24, 2003, claims **1-42** are pending in the application.

Priority

2. Receipt is acknowledged of papers submitted under 35 U.S.C. 119(a)-(d), which papers have been placed of record in the file.

Information Disclosure Statement

This office acknowledges receipt of the following items from the Applicant:
 Information Disclosure Statement (IDS) filed on April 27, 2004.
 Information disclosed and listed on PTO 1449 was considered.

Examiner's Statement of Reasons for Allowance

4. Claims **1-42** are allowed.

Wang et al. (US 6,525,970), Mihnea et al. (US 6,426,898), Chang (US 5,991,204), Chang et al. (US 5,940,325) and Chen et al. (US 5,561,620) disclose a nonvolatile semiconductor memory device having an erase operation similar to that of the present application, but fail to teach:

"a positive potential is applied to said first conductor, holes are injected into said charge accumulation portion, in which electrons are accumulated, and thereby an erase operation is performed" as claimed in the independent claim 1; or

"a current flows between said first and second semiconductor regions, holes are injected into said charge accumulation portion, in which electrons are accumulated, and thereby an erase operation is performed" as claimed in the independent claim 21; or

"a positive potential is applied to said first conductor, holes generated between said first and second semiconductor regions are injected into a portion, which is disposed near the end of said second insulator film and on a side of said first conductor, and thereby an erase operation is performed" as claimed in the independent claim 22; or

"a positive potential is applied to said first line connected with a selected memory cell of said plurality of memory cells, holes are injected into said charge accumulation portion of said selected memory cell, in which electrons are accumulated, and thereby an erase operation is performed" as claimed in the independent claim 23; or

"a positive potential is applied to said first line connected with a selected memory cell in said plurality of memory cells, holes are injected into said charge accumulation portion of said selected memory cell, in which electrons are accumulated, and thereby an erase operation is performed" as claimed in the independent claim 33.

Any comments considered necessary by applicants must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comment on Statement of Reasons for Allowance".

Conclusion

5. Any inquiry concerning this communication or earlier communications from the examiner should be directed to **ANH PHUNG** whose telephone number is **(571) 272-1883**. The examiner can normally be reached on Monday-Friday from 8:00 AM to 4:30 PM.

Page 4

Application/Control Number: 10/743,783

Art Unit: 2824

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, **RICHARD ELMS**, can be reached on **(571) 272-1869**. The fax phone number for the organization where this application or proceeding is assigned is **(703) 872-9306**.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Art Unit: 2824

AKP

ANH PHUNG PRIMARY EXAMINER

Cach Thung